

Vishay Siliconix

N-Channel 20 V (D-S) MOSFET

DESCRIPTION

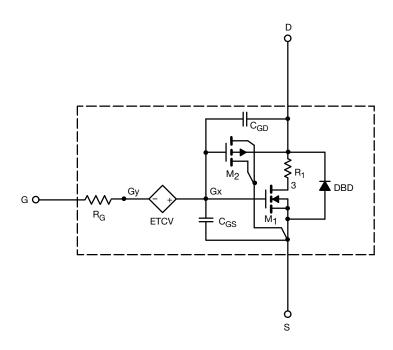
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model SiS410DN

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5	-	V
Drain-Source On-State Resistance ^a	В	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	0.004	0.004	Ω
	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 19.4 A	0.005	0.005	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, I_D = 20 \text{ A}$	80	70	S
Diode Forward Voltage	V _{SD}	I _S = 10 A	0.79	0.80	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	1560	1600	pF
Output Capacitance	C _{oss}		503	500	
Reverse Transfer Capacitance	C _{rss}		200	200	
Total Gate Charge	Qg	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 20 A	25	27	nC
		V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 20 A	13	16.7	
Gate-Source Charge	Q_{gs}		4.5	4.5	
Gate-Drain Charge	Q _{qd}		3.5	3.5	

Notes

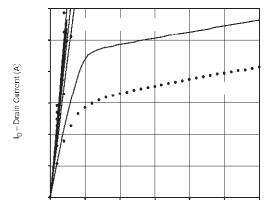
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

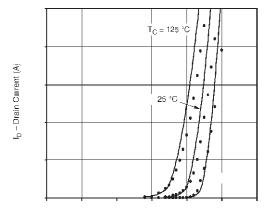
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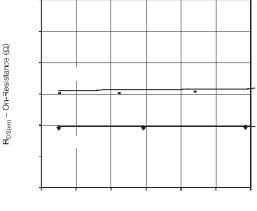
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}C$, unless otherwise noted)



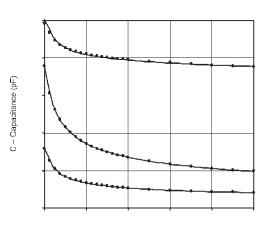




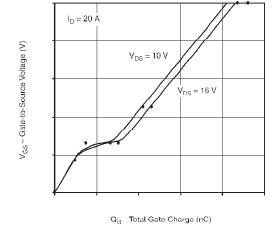
V_{GS} - Gate-to-Source Voltage (V)

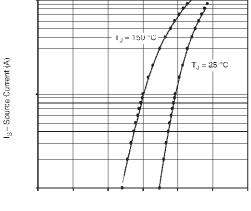


 I_{\square} - Drain Current (A)



 V_{DS} – Drain-to-Source Voltage (V)





 V_{SD} - Source to Drain Voltage (V)

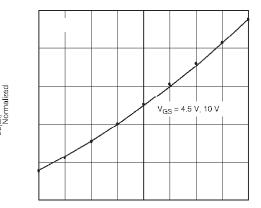
Note

• Dots and squares represent measured data.

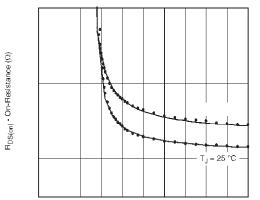
SPICE Device Model SiS410DN

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COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}\text{C}$, unless otherwise noted)



T_J- Junction Temperature (°C)



Note

• Dots and squares represent measured data.



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